



High Quality Audio , J-FET Input, Dual Operational Amplifier

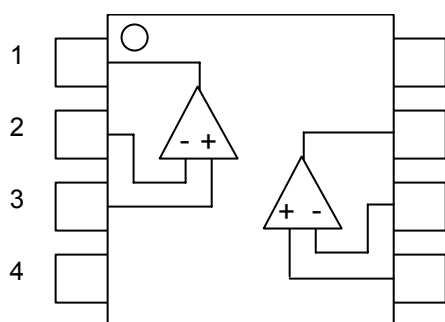
The **MUSES01** is a dual J-FET input high quality audio operational amplifier, which is optimized for high-end audio and professional audio applications with advanced circuitry and layout, unique material and assembled technology by skilled-craftwork.

It is the best for audio preamplifiers, active filters, and line amplifiers with excellent sound.

■ FEATURES

•Operating Voltage	$V_{opr} = \pm 9V$ to $\pm 16V$
•Output noise	$9.5nV/\sqrt{Hz}$ at $f=1kHz$
•Input Offset Voltage	$0.8mV$ typ. $5mV$ max.
•Input Bias Current	$200pA$ typ. $800pA$ max. at $T_a=25^\circ C$
•Voltage Gain	$105dB$ typ.
•Slew Rate	$12V/\mu s$ typ.
•Bipolar Technology	
•Package Outline	DIP8

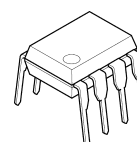
■ PIN CONFIGURATION



PIN FUNCTION

- | | |
|----|----------|
| 1. | A OUTPUT |
| 2. | A -INPUT |
| 3. | A +INPUT |
| 4. | V- |
| 5. | B +INPUT |
| 6. | B -INPUT |
| 7. | B OUTPUT |
| 8. | V+ |

■ PACKAGE OUTLINE



MUSES01D



MUSES and this logo are trademarks of New Japan Radio Co., Ltd.

MUSES01

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V^+/V^-	± 18	V
Common Mode Input Voltage	V_{ICM}	± 15 (Note1)	V
Differential Input Voltage	V_{ID}	± 30	V
Power Dissipation	P_D	910	mW
Output Current	I_O	± 25	mA
Operating Temperature Range	T_{opr}	-40 to +85	°C
Storage Temperature Range	T_{stg}	-50 to +150	°C

(Note1) For supply Voltages less than ± 15 V, the maximum input voltage is equal to the Supply Voltage.

■ RECOMMENDED OPERATING CONDITION (Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V^+/V^-	-	± 9	-	± 16	V

■ ELECTRIC CHARACTERISTICS

DC CHARACTERISTICS ($V^+/V^- = \pm 15$ V, Ta=25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Current	I_{cc}	No Signal, $R_L = \infty$	-	8.5	12.0	mA
Input Offset Voltage	V_{IO}	$R_s \leq 10k\Omega$ (Note2, 3)	-	0.8	5.0	mV
Input Bias Current	I_B	(Note2, 3)	-	200	800	pA
Input Offset Current	I_{IO}	(Note2, 3)	-	100	400	pA
Voltage Gain	A_V	$R_L \geq 2k\Omega$, $V_o = \pm 10$ V	90	105	-	dB
Common Mode Rejection Ratio	CMR	$V_{ICM} = \pm 8$ V (Note4)	60	75	-	dB
Supply Voltage Rejection Ratio	SVR	$V^+/V^- = \pm 9.0$ to ± 16.0 V (Note2, 5)	70	83	-	dB
Max Output Voltage 1	V_{OM1}	$R_L = 10k\Omega$	± 12	± 13.5	-	V
Max Output Voltage 2	V_{OM2}	$R_L = 2k\Omega$	± 10	± 12.5	-	V
Input Common Mode Voltage Range	V_{ICM}	CMR ≥ 60 dB	± 8	± 9.5	-	V

(Note2) Measured at $V_{ICM} = 0$ V

(Note3) Written by the absolute rate.

(Note4) CMR is calculated by specified change in offset voltage. ($V_{ICM} = 0$ V to +8 V and $V_{ICM} = 0$ V to -8 V)

(Note5) SVR is calculated by specified change in offset voltage. ($V^+/V^- = \pm 9$ V to ± 16 V)

AC CHARACTERISTICS ($V^+/V^- = \pm 15V$, $T_a = 25^\circ C$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gain Bandwidth Product	GB	$f = 10kHz$	-	3.3	-	MHz
Unity Gain Frequency	f_T	$A_V = +100$, $R_S = 100\Omega$, $R_L = 2k\Omega$, $C_L = 10pF$	-	3.0	-	MHz
Phase Margin	ϕ_M	$A_V = +100$, $R_S = 100\Omega$, $R_L = 2k\Omega$, $C_L = 10pF$	-	60	-	deg
Input Noise Voltage1	V_{NI}	$f = 1kHz$, $A_V = +100$, $R_S = 100\Omega$	-	9.5	-	nV/ $\sqrt{Hz}$
Input Noise Voltage2	V_{N2}	RIAA, $R_S = 2.2k\Omega$, 30kHz LPF	-	1.2	3.0	μV_{rms}
Total Harmonic Distortion	THD	$f = 1kHz$, $A_V = +10$, $R_L = 2k\Omega$, $V_o = 5V_{rms}$	-	0.002	-	%
Channel Separation	CS	$f = 1kHz$, $A_V = +100$, $R_S = 1k\Omega$, $R_L = 2k\Omega$	-	150	-	dB
Positive Slew Rate	+SR	$A_V = 1$, $V_{IN} = 2V_{p-p}$, $R_L = 2k\Omega$, $C_L = 10pF$	-	12	-	V/ μs
Negative Slew Rate	-SR	$A_V = 1$, $V_{IN} = 2V_{p-p}$, $R_L = 2k\Omega$, $C_L = 10pF$	-	13	-	V/ μs

■ Application Notes

•Package Power, Power Dissipation and Output Power

IC is heated by own operation and possibly gets damage when the junction power exceeds the acceptable value called Power Dissipation P_D . The dependence of the MUSES01 P_D on ambient temperature is shown in Fig 1. The plots are depended on following two points. The first is P_D on ambient temperature 25°C, which is the maximum power dissipation. The second is 0W, which means that the IC cannot radiate any more. Conforming the maximum junction temperature T_{jmax} to the storage temperature T_{stg} derives this point. Fig.1 is drawn by connecting those points and conforming the P_D lower than 25°C to it on 25°C. The P_D is shown following formula as a function of the ambient temperature between those points.

$$\text{Dissipation Power } P_D = \frac{T_{jmax} - T_a}{\theta_{ja}} \text{ [W]} \quad (T_a=25^\circ\text{C to } T_a=150^\circ\text{C})$$

Where, θ_{ja} is heat thermal resistance which depends on parameters such as package material, frame material and so on. Therefore, P_D is different in each package.

While, the actual measurement of dissipation power on MUSES01 is obtained using following equation.

$$(\text{Actual Dissipation Power}) = (\text{Supply Voltage } V_{DD}) \times (\text{Supply Current } I_{DD}) - (\text{Output Power } P_o)$$

The MUSES01 should be operated in lower than P_D of the actual dissipation power.

To sustain the steady state operation, take account of the Dissipation Power and thermal design.

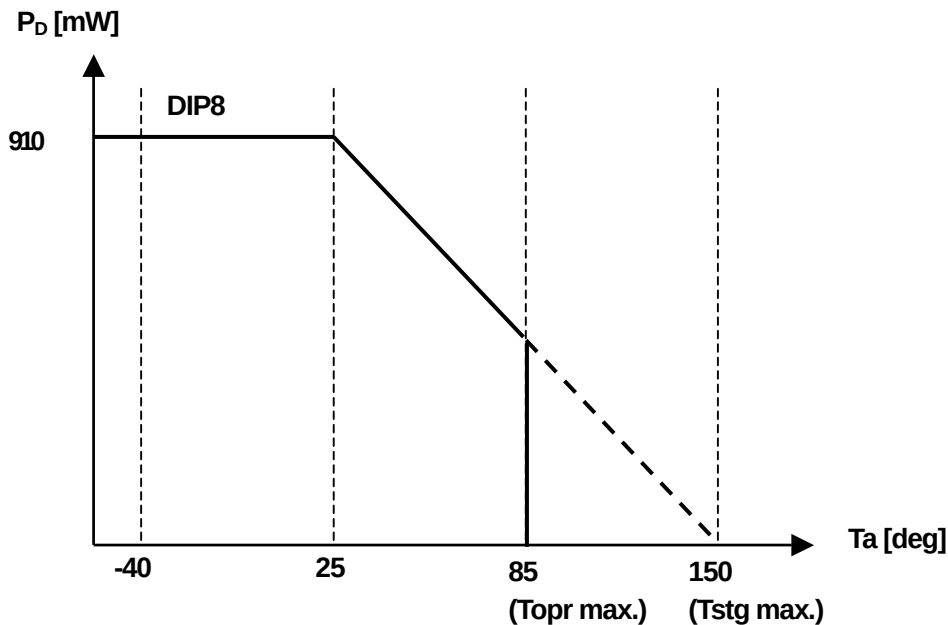
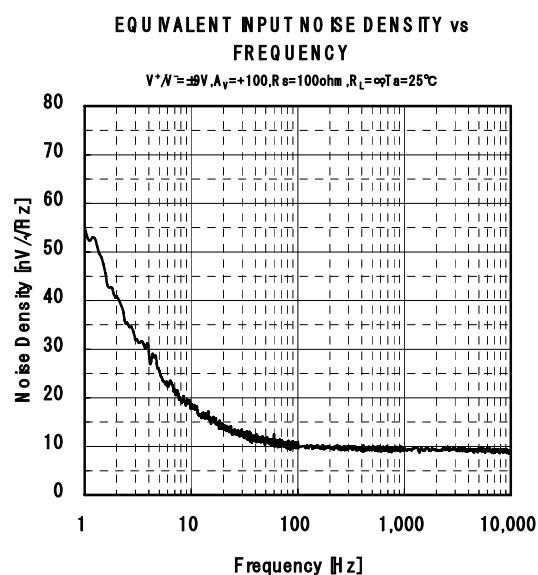
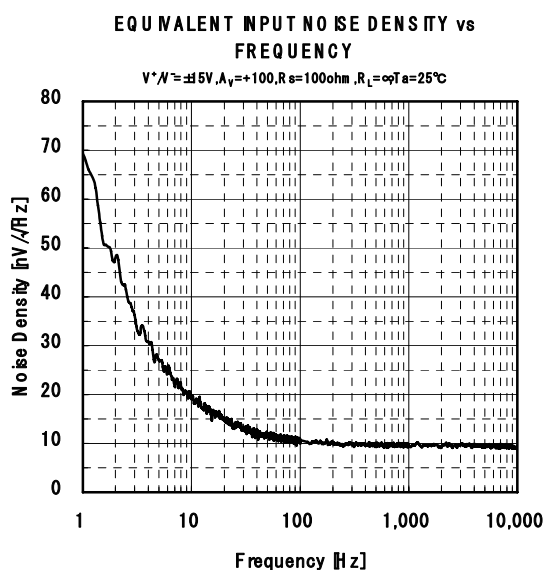
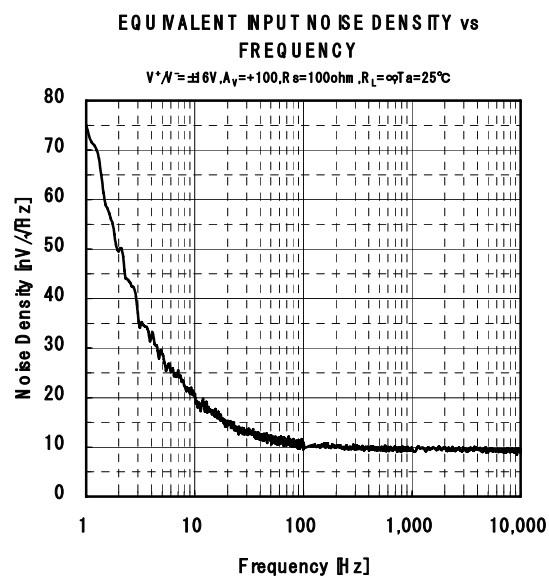
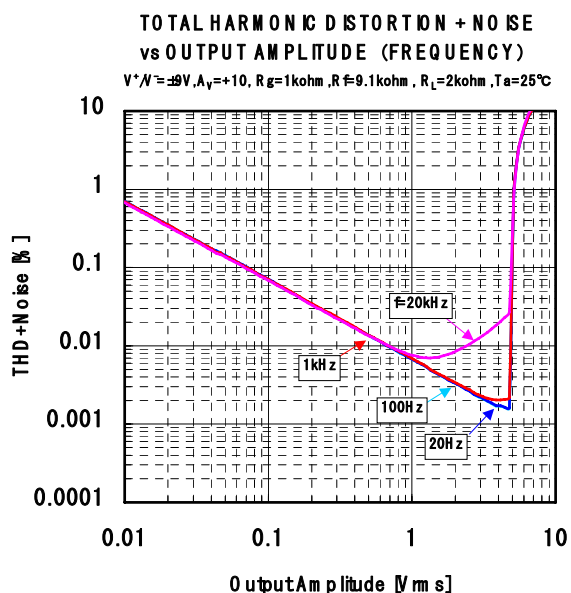
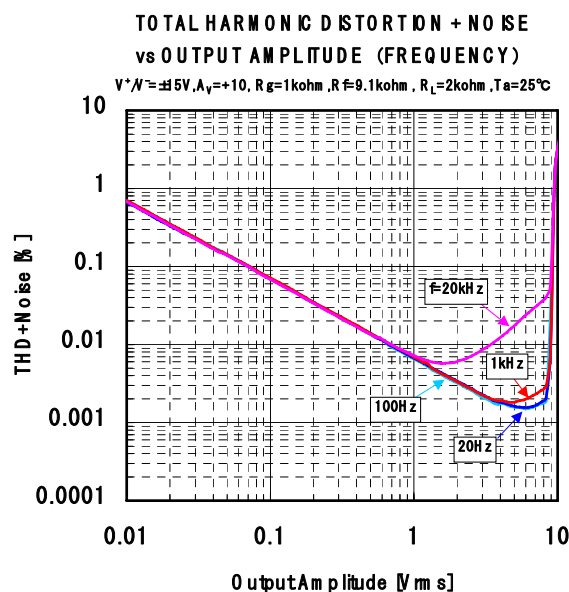
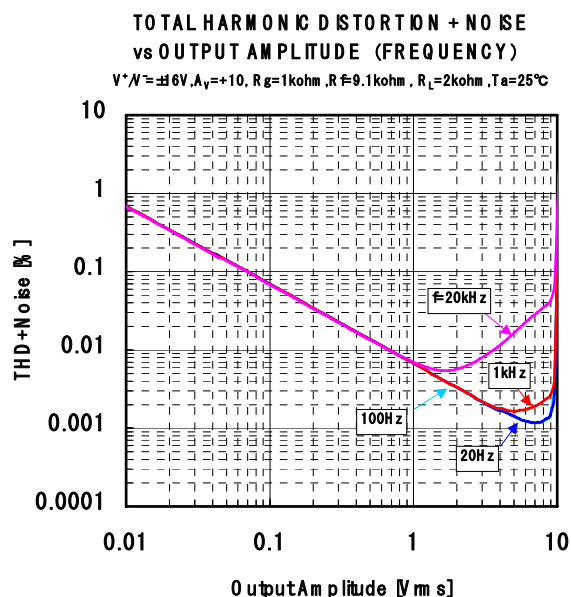
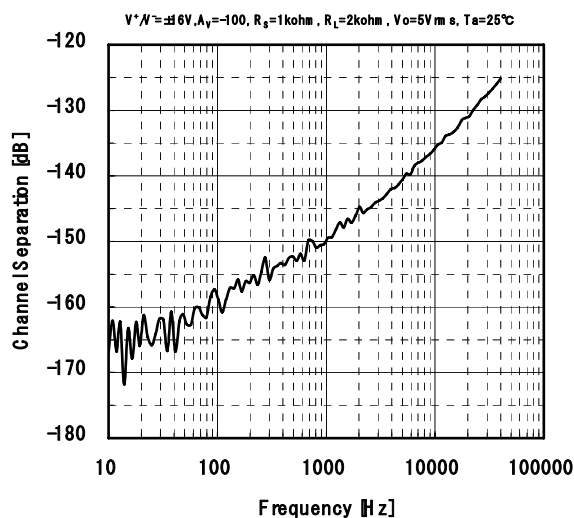


Fig.1 Power Dissipations vs. Ambient Temperature on the MUSES01

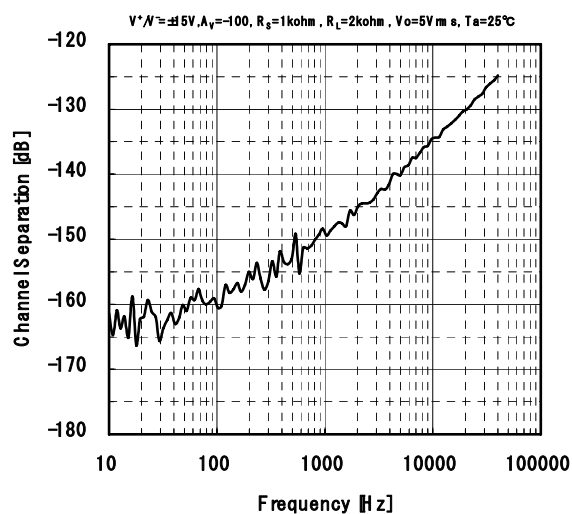
■ TYPICAL CHARACTERISTICS



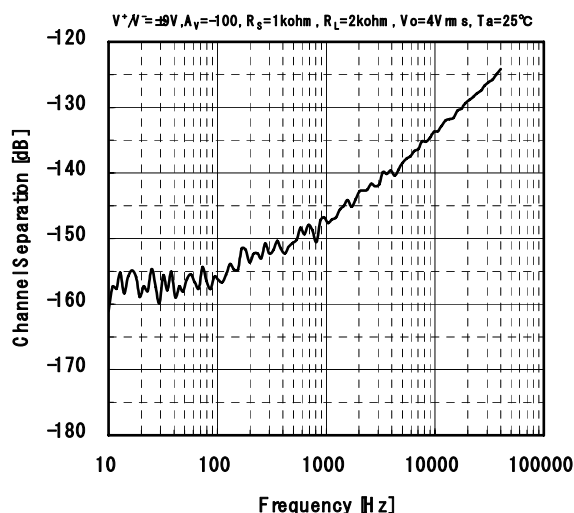
CHANNEL SEPARATION vs FREQUENCY



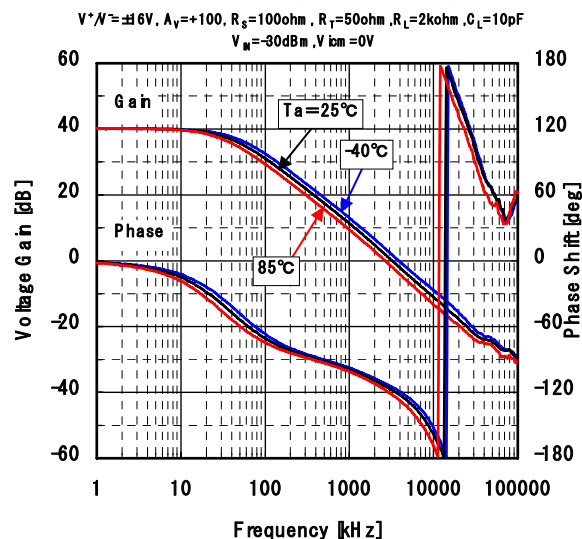
CHANNEL SEPARATION vs FREQUENCY



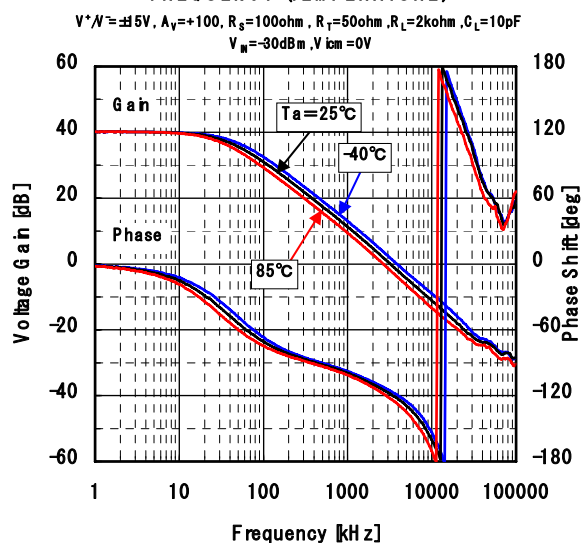
CHANNEL SEPARATION vs FREQUENCY



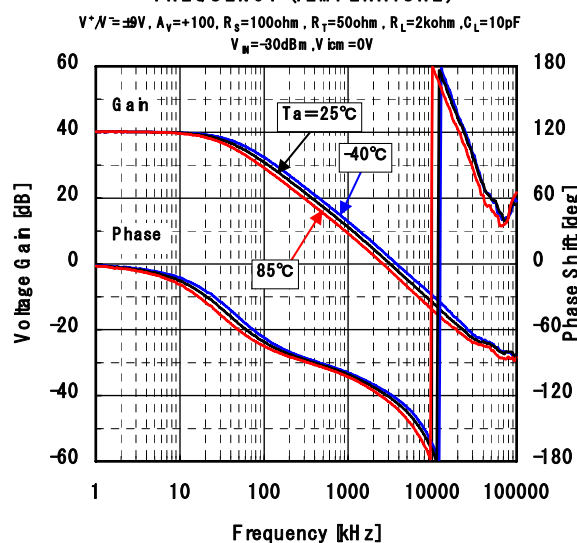
CLOSED-LOOP GAIN/PHASE vs FREQUENCY (TEMPERATURE)



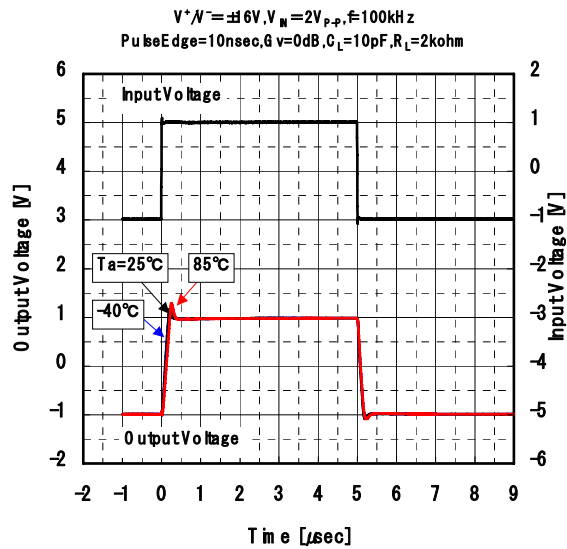
CLOSED-LOOP GAIN/PHASE vs FREQUENCY (TEMPERATURE)



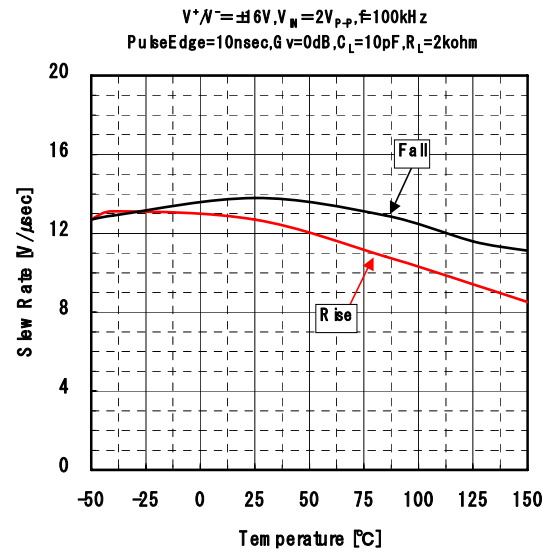
CLOSED LOOP GAIN/PHASE vs FREQUENCY (TEMPERATURE)



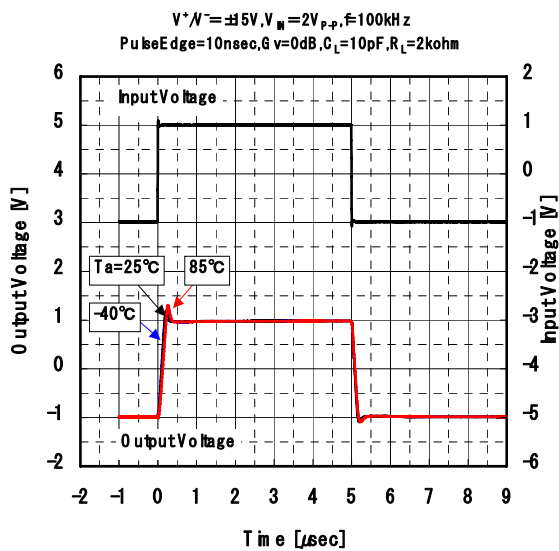
TRANSIENT RESPONSE (TEMPERATURE)



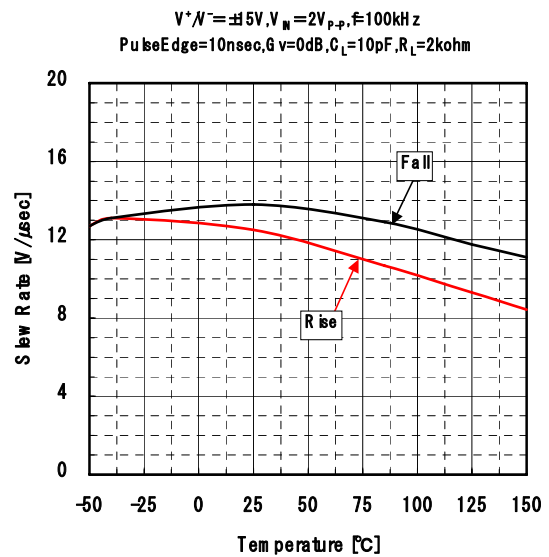
SLEW RATE vs TEMPERATURE



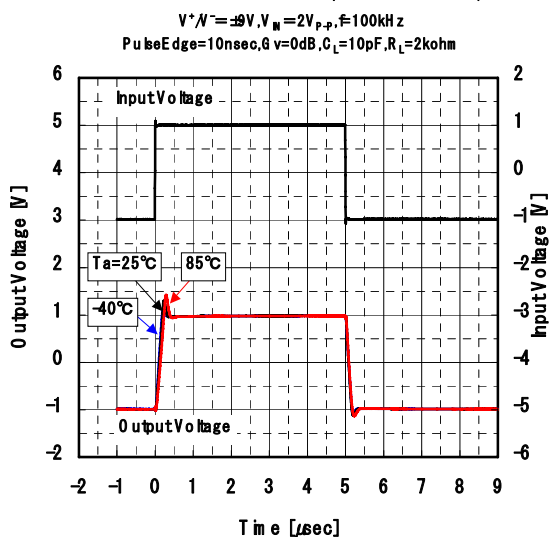
TRANSIENT RESPONSE (TEMPERATURE)



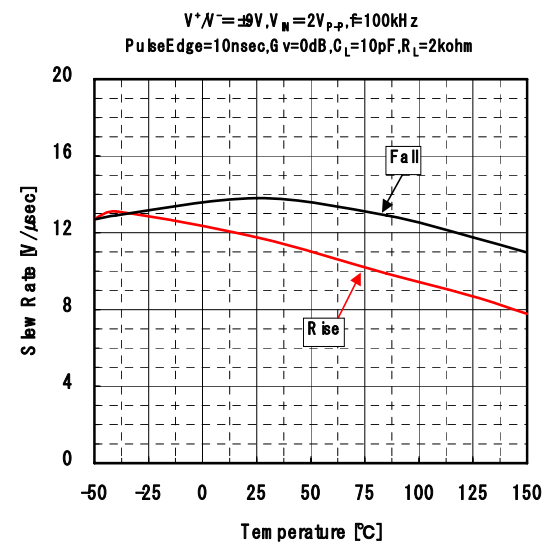
SLEW RATE vs TEMPERATURE

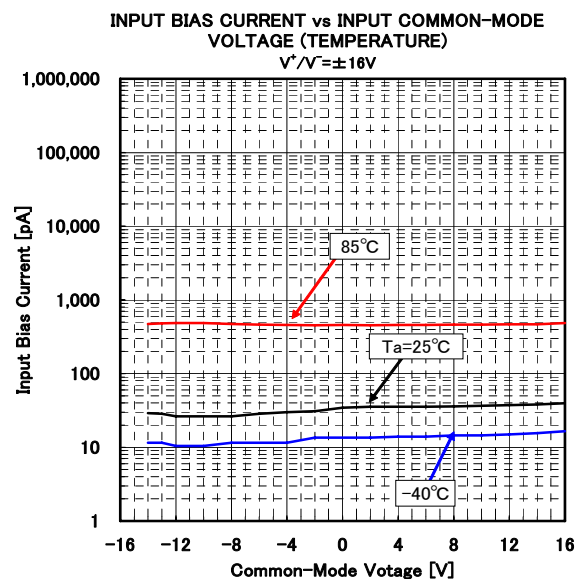
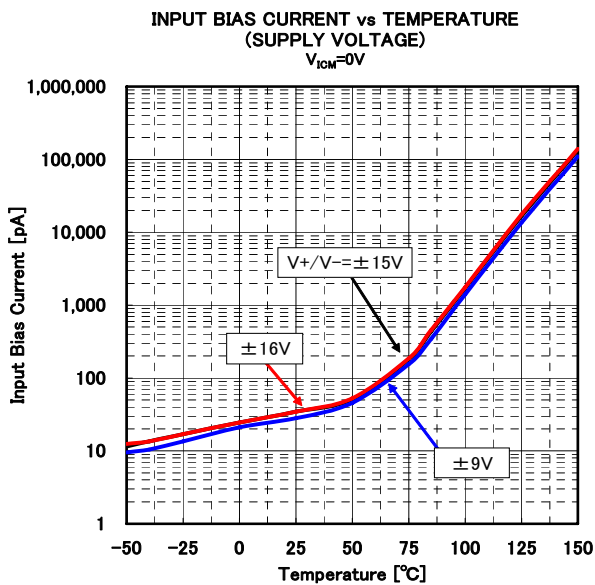
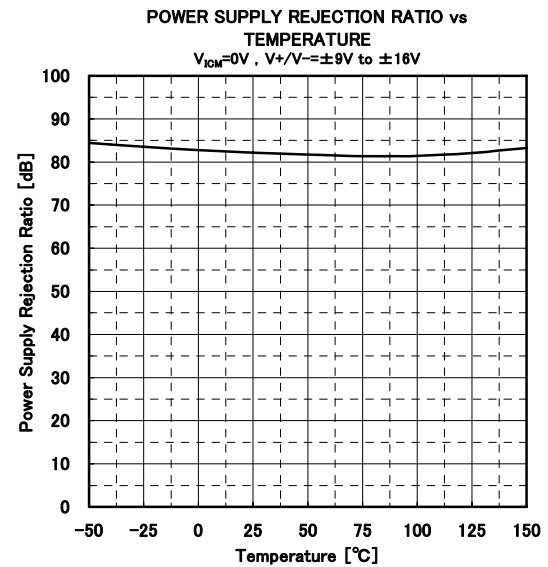
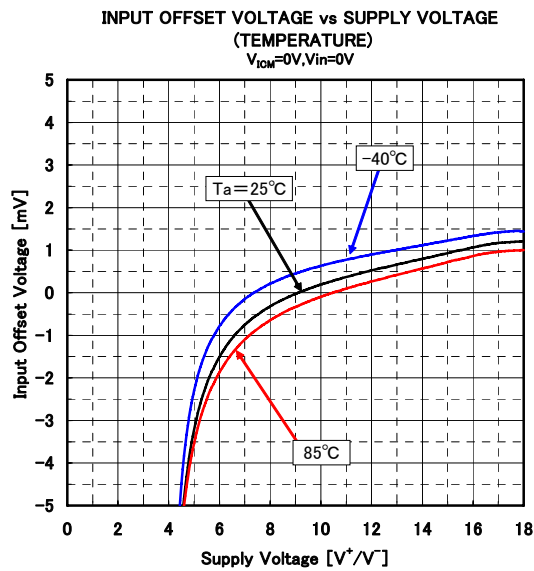
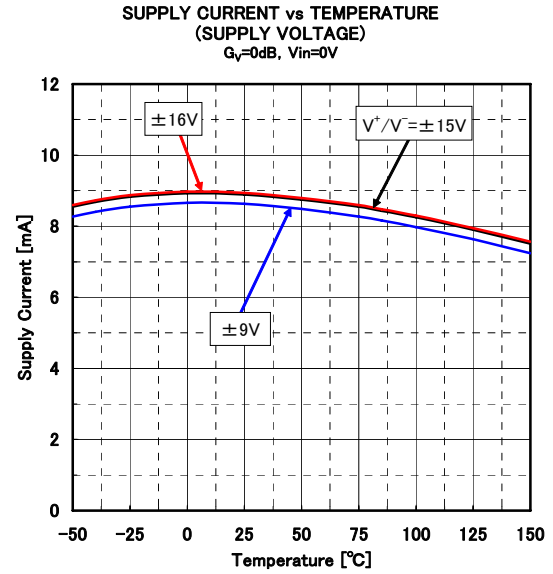
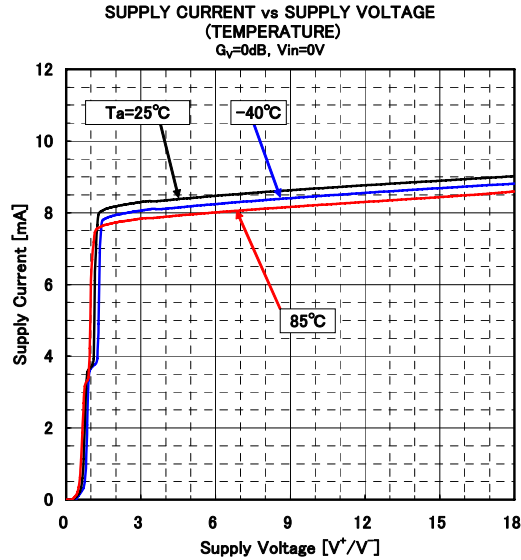


TRANSIENT RESPONSE (TEMPERATURE)

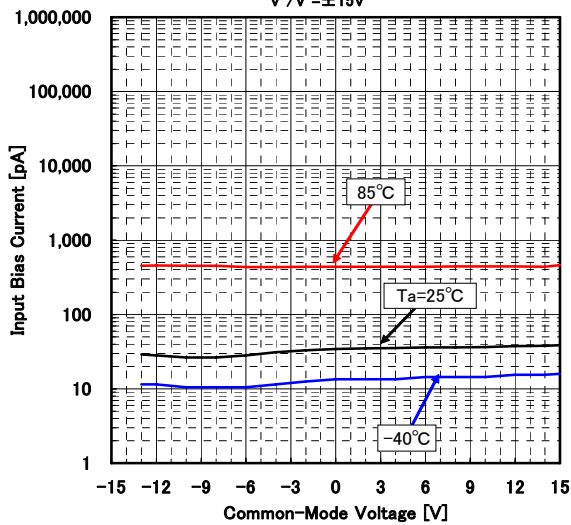


SLEW RATE vs TEMPERATURE

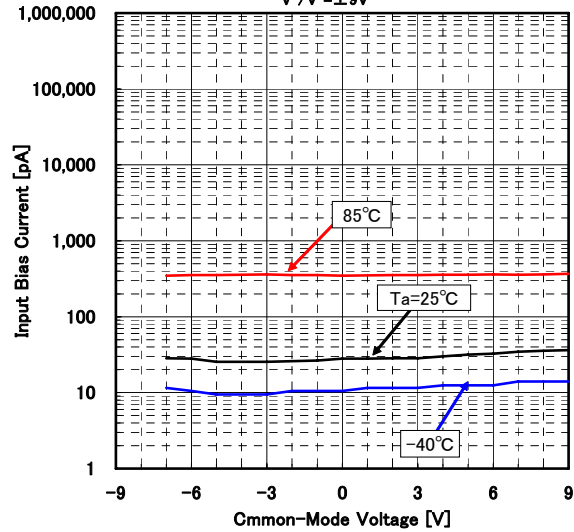




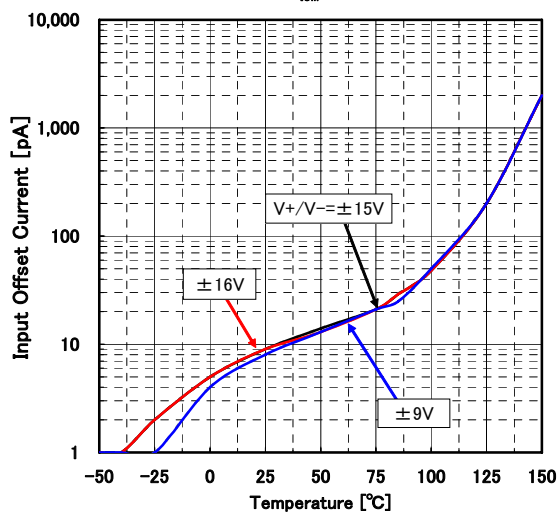
INPUT BIAS CURRENT vs INPUT COMMON-MODE VOLTAGE (TEMPERATURE)
 $V^+/V^- = \pm 15V$



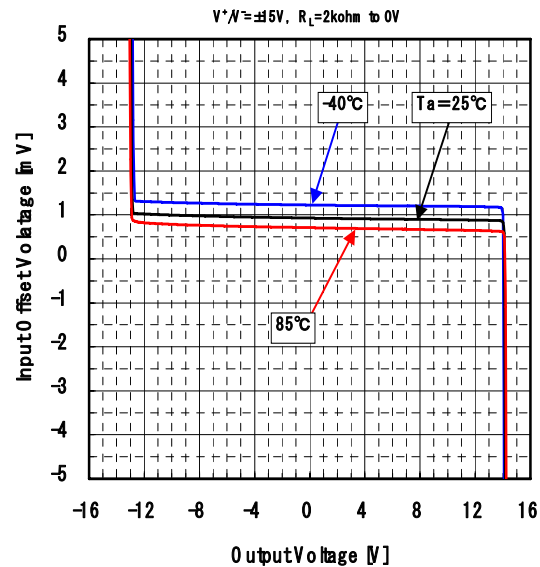
INPUT BIAS CURRENT vs INPUT COMMON-MODE VOLTAGE (TEMPERATURE)
 $V^+/V^- = \pm 9V$



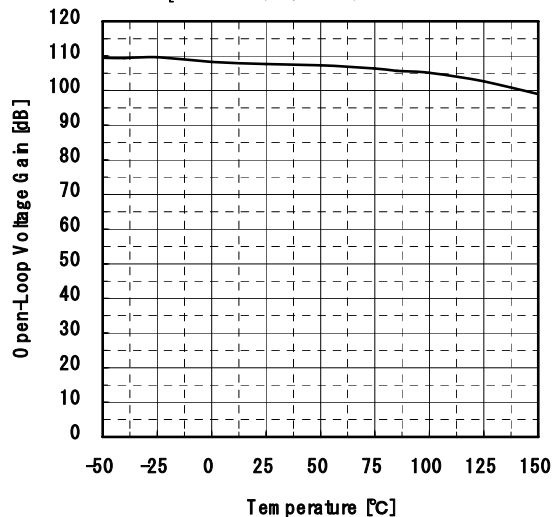
INPUT OFFSET CURRENT vs TEMPERATURE (SUPPLY VOLTAGE)
 $V_{CM}=0V$



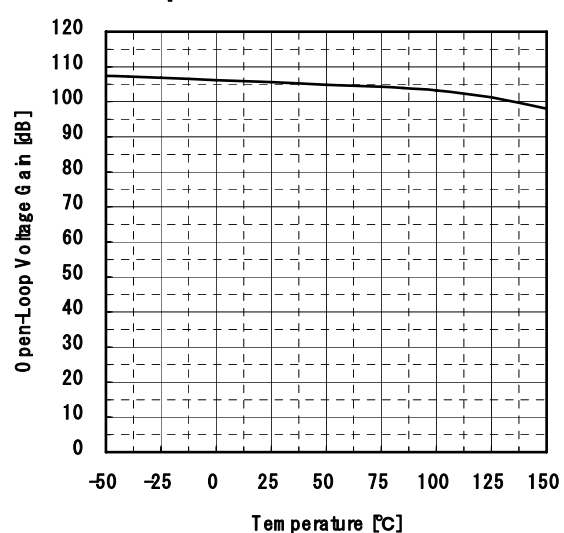
INPUT OFFSET VOLTAGE vs OUTPUT VOLTAGE (TEMPERATURE)
 $V^+/V^- = \pm 5V, R_L = 2k\Omega \text{ to } 0V$



OPEN-LOOP VOLTAGE GAIN vs TEMPERATURE
 $R_L = 2k\Omega \text{ to } 0V, V^+/V^- = \pm 6V, V_O = -11V \text{ to } +11V$

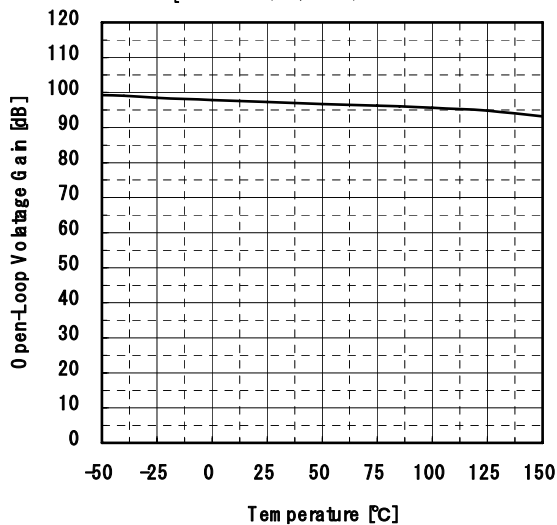


OPEN-LOOP VOLTAGE GAIN vs TEMPERATURE
 $R_L = 2k\Omega \text{ to } 0V, V^+/V^- = \pm 5V, V_O = -10V \text{ to } +10V$



OPEN-LOOP VOLTAGE GAIN vs TEMPERATURE

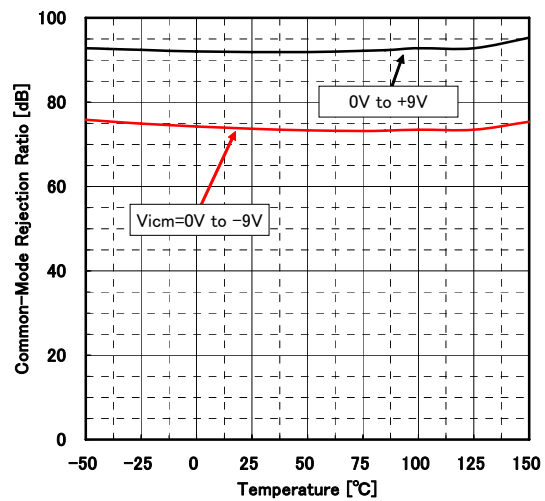
$R_L = 2\text{k}\Omega$ to 0V, $V^+ / V^- = \pm 9V$, $V_O = -4V$ to +4V



COMMON-MODE REJECTION RATIO vs TEMPERATURE

(INPUT COMMON-MODE VOLTAGE)

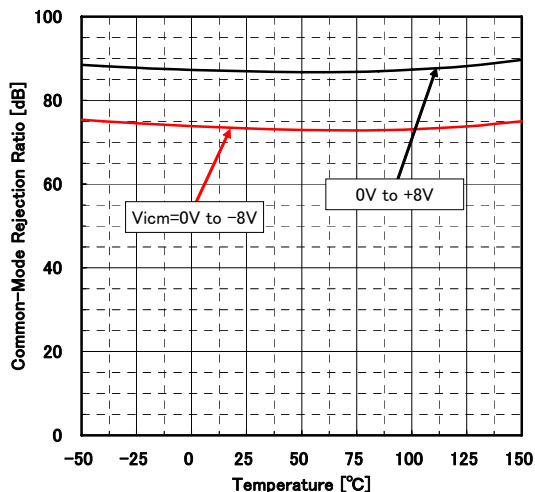
$V^+ / V^- = \pm 16V$



COMMON-MODE REJECTION RATIO vs TEMPERATURE

(INPUT COMMON-MODE VOLTAGE)

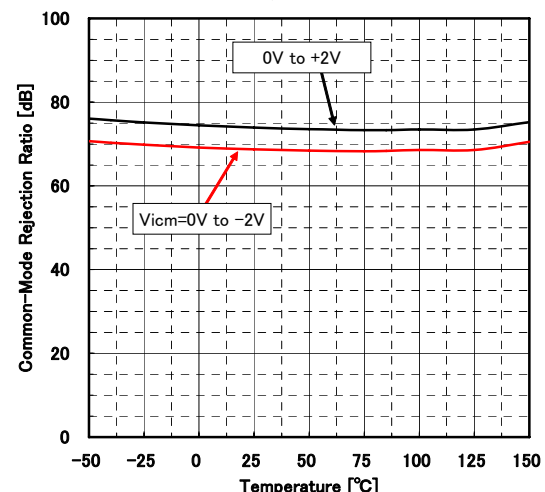
$V^+ / V^- = \pm 15V$



COMMON-MODE REJECTION RATIO vs TEMPERATURE

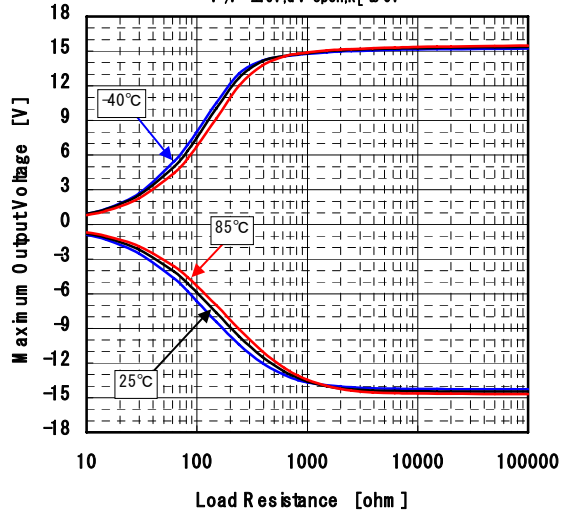
(INPUT COMMON-MODE VOLTAGE)

$V^+ / V^- = \pm 9V$



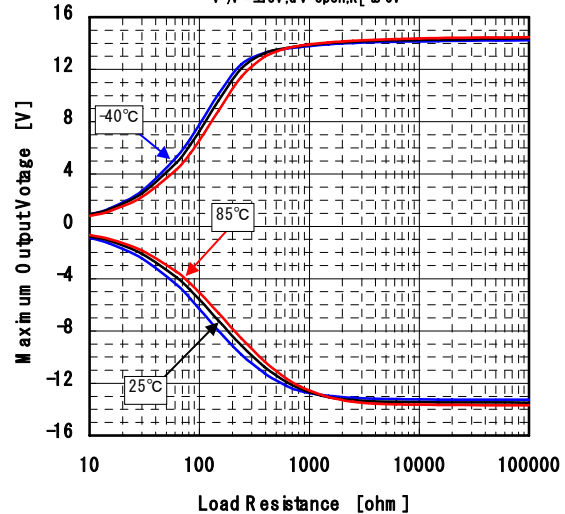
MAXIMUM OUTPUT VOLTAGE vs LOAD RESISTANCE (TEMPERATURE)

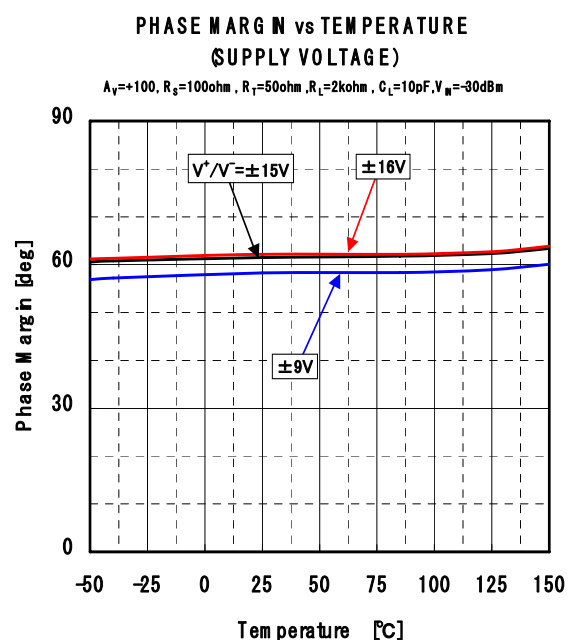
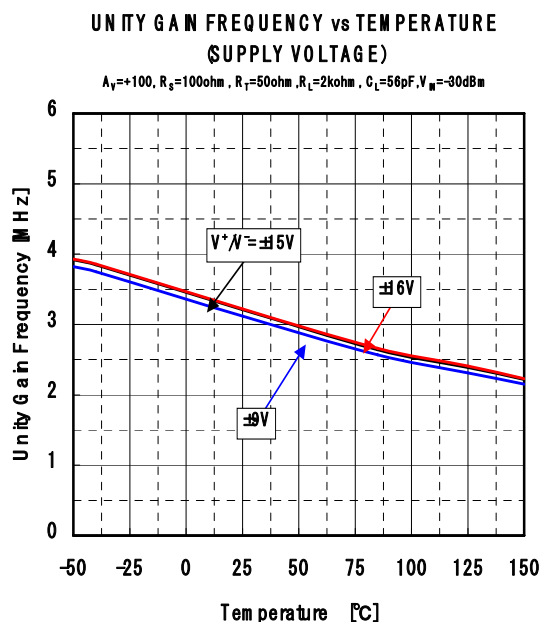
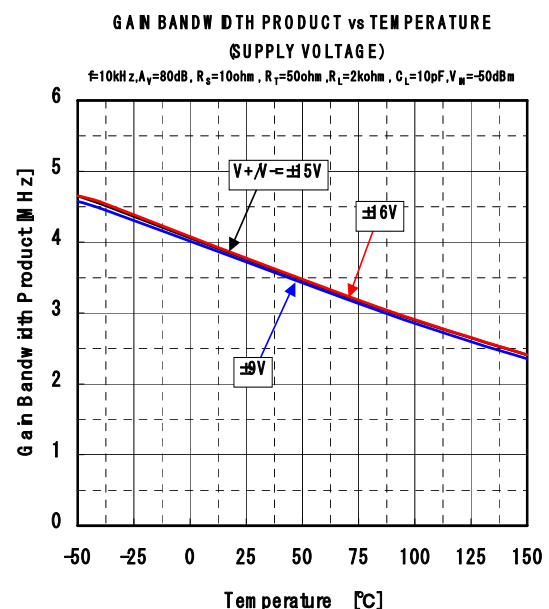
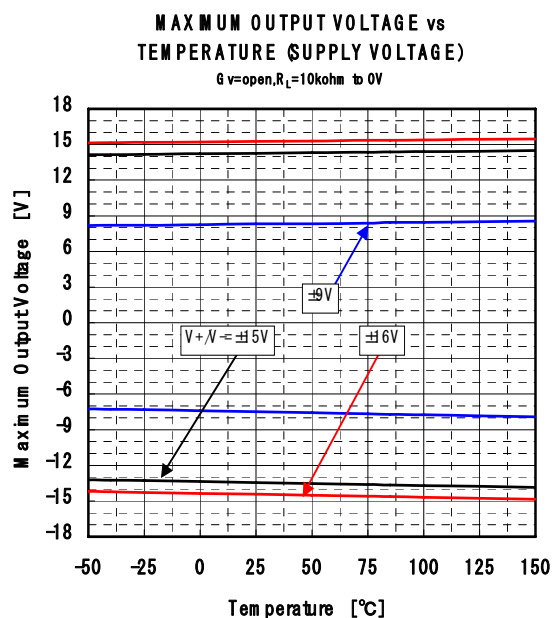
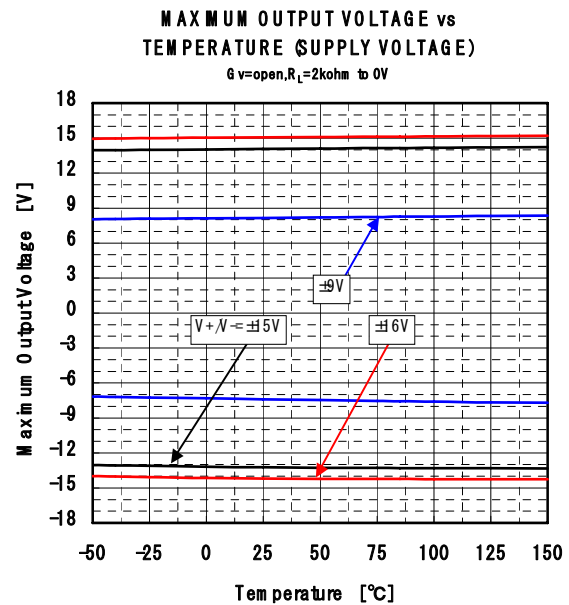
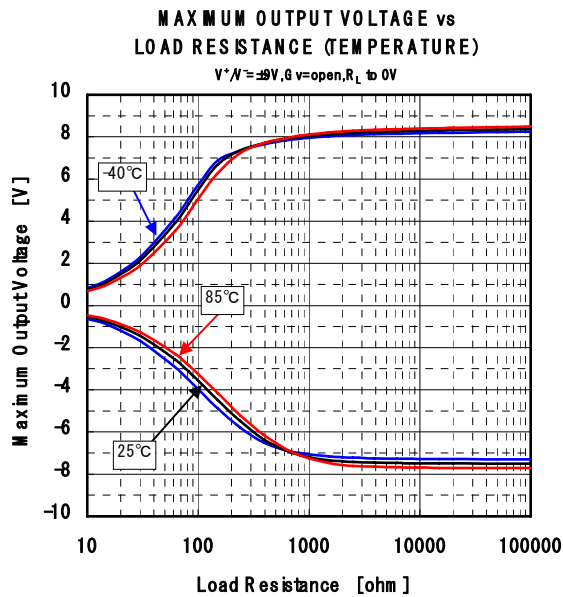
$V^+ / V^- = \pm 6V$, $G_v = \text{open}$, R_L to 0V



MAXIMUM OUTPUT VOLTAGE vs LOAD RESISTANCE (TEMPERATURE)

$V^+ / V^- = \pm 5V$, $G_v = \text{open}$, R_L to 0V





MEMO

[CAUTION]
The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А